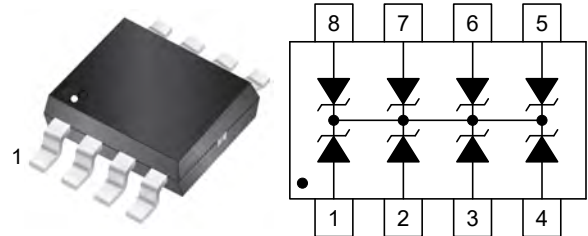


Features

- 300Watts peak pulse power ($t_p = 8/20\mu s$)
- SOIC-8 Package
- Protects Seven I/O lines
- Low clamping voltage
- Low leakage current
- Low capacitance
- Transient protection for high-speed data lines to :
 - IEC 61000-4-2 (ESD) $\pm 30kV$ (air), $\pm 30kV$ (contact)
 - IEC 61000-4-4 (EFT) 40A (5/50ns)
 - IEC 61000-4-5 (Lightning)12A (8/20 μs)



Mechanical Data

- **Case:** SOIC-8 (plastic package).
Lead free; RoHS compliant; Halogen free
- **Molding Compound Flammability Rating:**
UL 94 V-0
- **Terminals:** High temperature soldering guaranteed:
260 °C/10 sec. at terminals

Applications

- I²C serial ports
- LAN/WAN equipment
- Set Top Box (STB)
- Peripherals
- Microprocessor based equipment
- Notebooks, desktops, servers
- RS-232 and RS-422 data line protection

Absolute Maximum Ratings

Ratings at 25 °C, ambient temperature unless otherwise specified

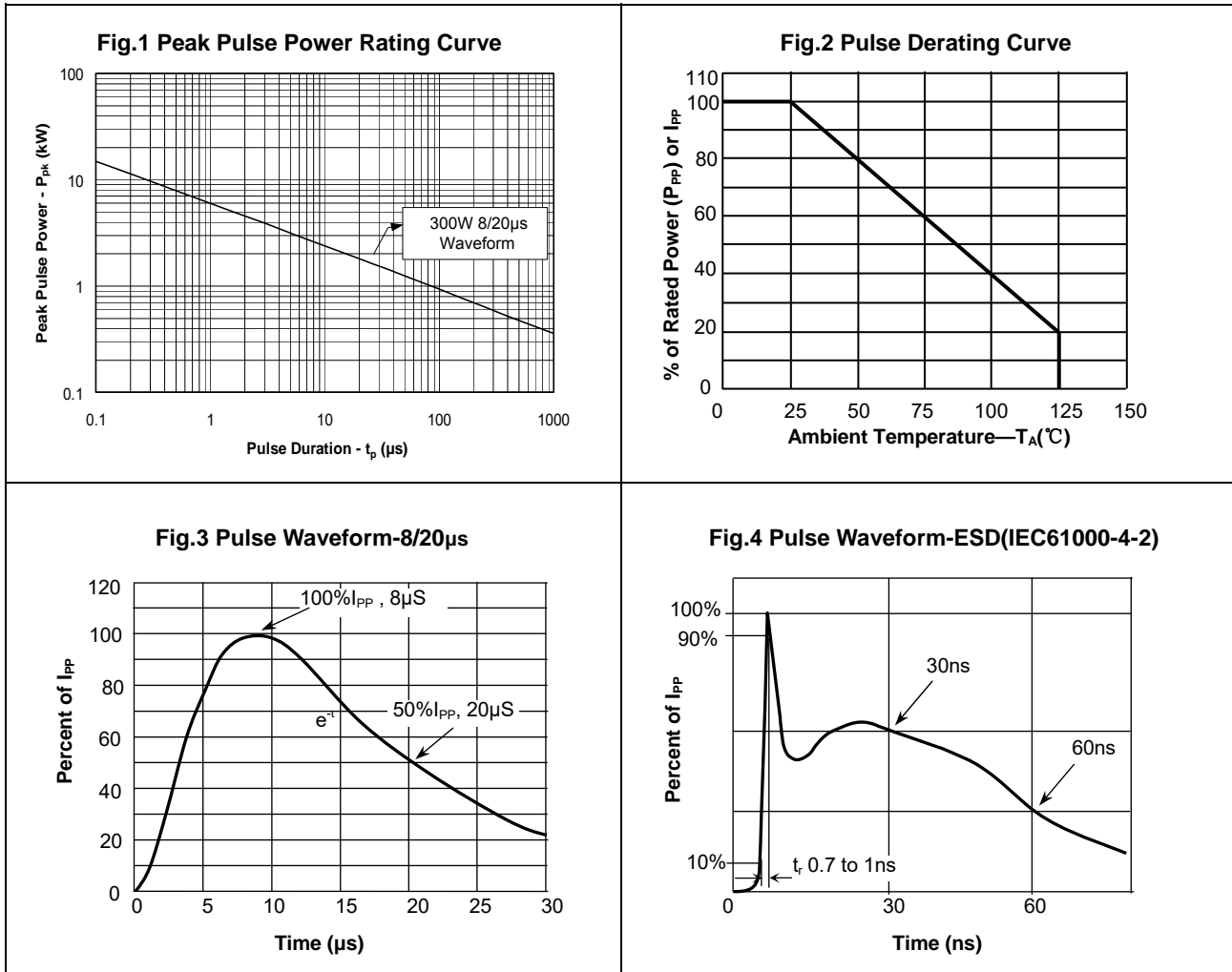
Parameter	Symbol	Value	Unit
Peak Pulse Power ($T_P=8/20\mu s$)	P_{PP}	300	W
ESD contact/air discharge (IEC-61000-4-2)	V_{ESD}	30/30	kV
Peak Pulse Current ($t_P = 8/20\mu s$)	I_{PP}	12	A
Junction Temperature	T_J	-55 to +125	°C
Storage temperature	T_{STG}	-55 to +150	°C

Electrical Characteristics

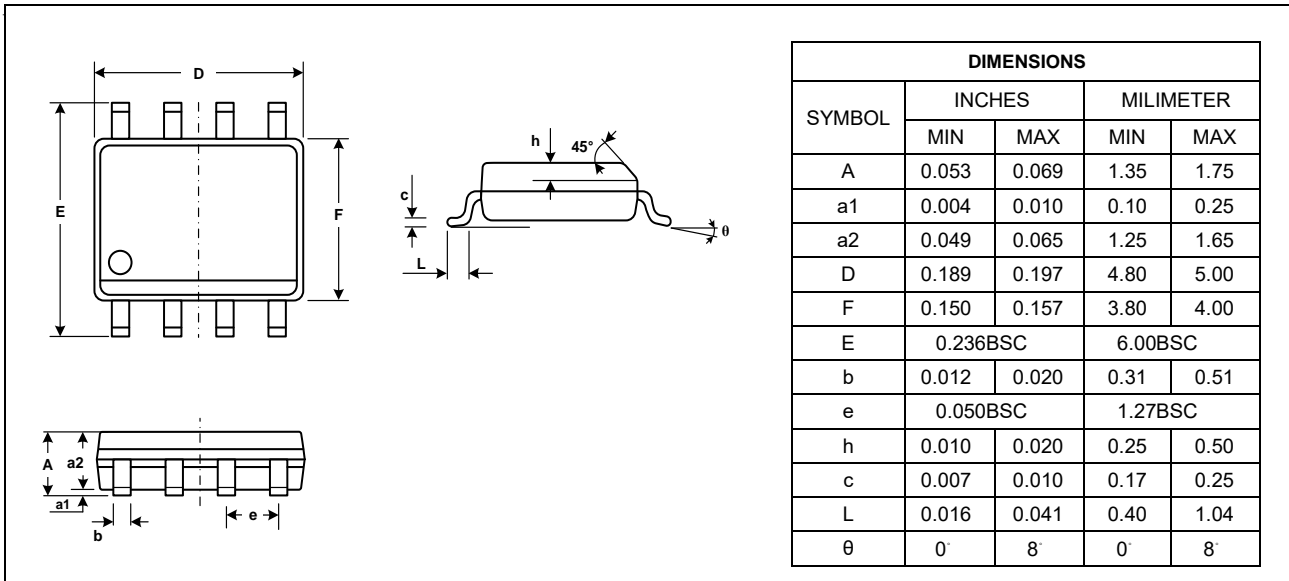
($T_A = 25\text{ °C}$ unless otherwise specified)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Reverse stand-off Voltage	V_{RWM}				15	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	16.7			V
Reverse Leakage Current	I_R	$V_R=15V$			0.5	μA
Clamping Voltage	V_C	$I_{PP}=12A, T_P=8/20\mu s$			27	V
Junction Capacitance	C_J	$V_R=0V, f=1MHz$; Between I/O pins and GND		30		pF

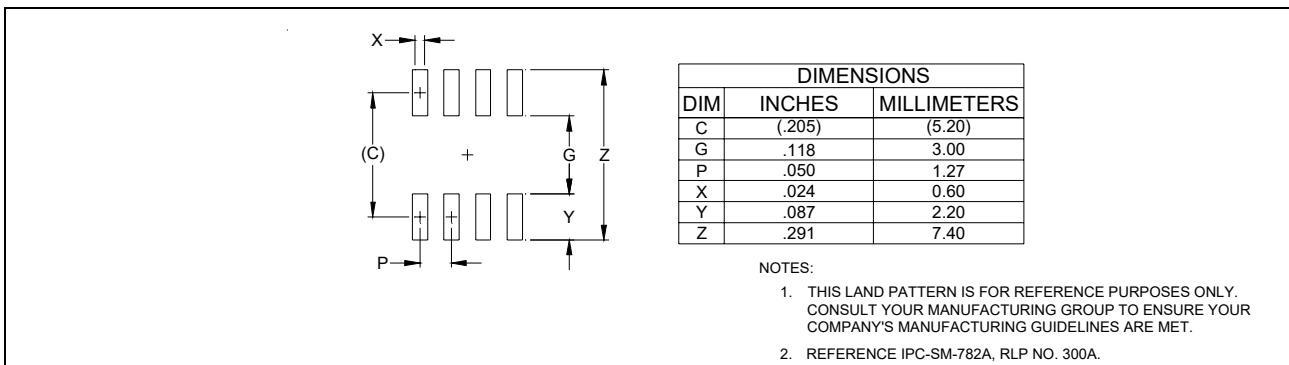
Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)



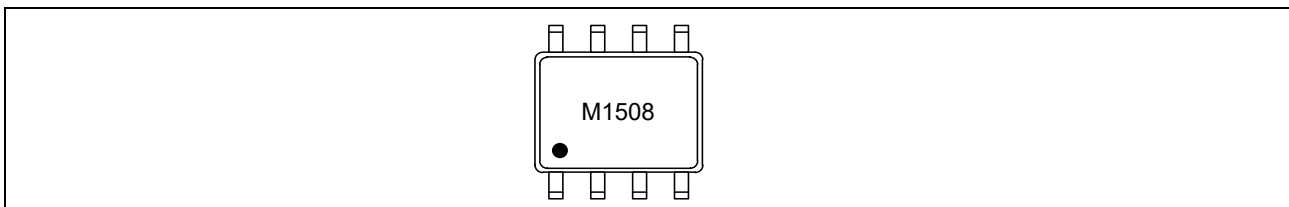
Package Dimensions



Pad Dimensions



Marking



Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
YEDSOP81512AV	SOIC-8	Tape and reel	2500pcs / reel	EIA STD RS-481